

1. General description

Planar passivated four quadrant triac in a SOT78 (TO-220AB) plastic package intended for use in general purpose bidirectional switching and phase control applications, where high sensitivity is required in all four quadrants. This very sensitive gate "series D" triac is intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

2. Features and benefits

- · Direct triggering from low power drivers and logic ICs
 - High blocking voltage capability
- · Low holding current for low current loads and lowest EMI at commutation
- · Planar passivated for voltage ruggedness and reliability
- Triggering in all four quadrants
- Very sensitive gate for easy logic level triggering

3. Applications

- General purpose motor controls
- General purpose switching

4. Quick reference data

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Table 1. Quick reference data

Symbol	Parameter	Conditions Min Typ		Max	Unit	
V_{DRM}	repetitive peak off-state voltage	٤ ٤		800	V	
$\mathbf{I}_{\mathrm{T}(\mathrm{RMS})}$	RMS on-state current	full sine wave; T _{mb} ≤ 110 °C; 4 <u>Fig. 1; Fig. 2; Fig. 3</u>		4	A	
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4; Fig. 5</u>	-	-	35	A
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics		· ·	· ·		
I _{GT} gate trigg	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u>	-	-	5	mA
		V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>	-	-	5	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u>	-	-	5	mA
		V _D = 12 V; I _T = 0.1 A; T2- G+; T _i = 25 °C; <u>Fig. 7</u>	-	-	10	mA

5. Pinning information

Table 2.	able 2. Pinning information						
Pin	Symbol	Description	Simplified outline	Graphic symbol			
1	T1	main terminal 1	mb				
2	T2	main terminal 2	ך ⊖ ך	Ν			
3	G	gate					
mb	T2	mounting base; main terminal 2		Sym051			

6. Ordering information

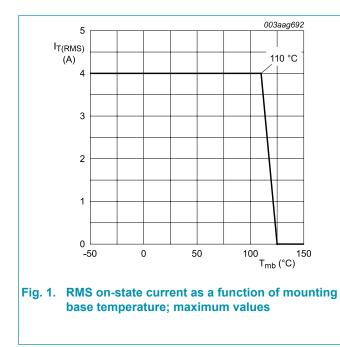
Table 3. Ordering information					
Type number	Package				
	Name	Description	Version		
		plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78		

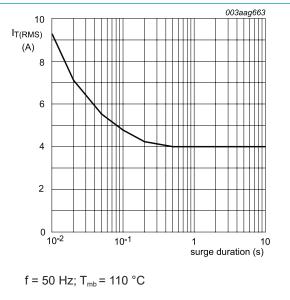
7. Limiting values

Table 4. Limiting values

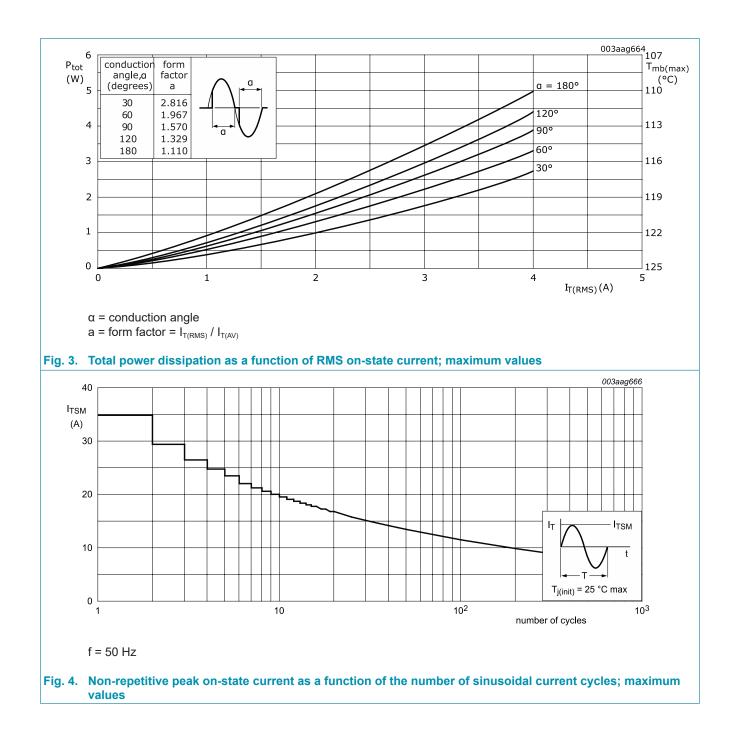
In accordance with the Absolute Maximum Rating System (IEC 60134).

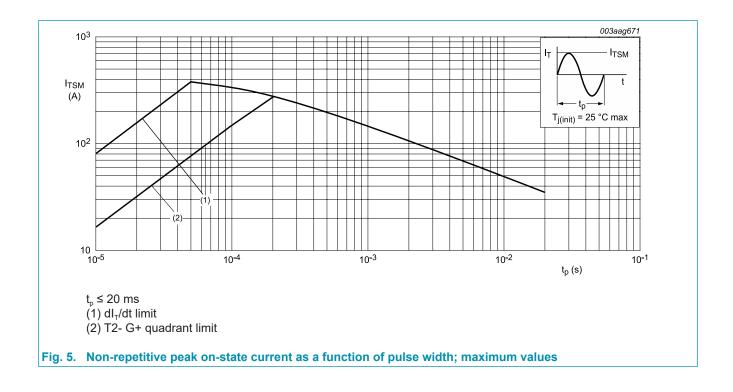
Symbol	Parameter	Conditions	Min	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	800	V
$I_{\mathrm{T}(\mathrm{RMS})}$	RMS on-state current	full sine wave; $T_{mb} \le 110 \text{ °C}$;-2Fig. 1; Fig. 2; Fig. 3-2		4	A
I _{TSM}	non-repetitive peak on-state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig 4; Fig 5</u>	-	35	A
		full sine wave; T _{j(init)} = 25 °C; t _p = 16.7 ms	-	38.5	A
l²t	l ² t for fusing	t _p = 10 ms; sine-wave pulse	-	6.1	A ² s
dl _⊤ /dt	rate of rise of on-state current	I _G = 10 mA; T2+ G+	-	50	A/µs
		I _G = 10 mA; T2+ G-		50	A/µs
		I _G = 10 mA; T2- G-		50	A/µs
		I _G = 20 mA; T2- G+		10	A/µs
I _{GM}	peak gate current		-	2	А
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
T _i	junction temperature		-	125	°C





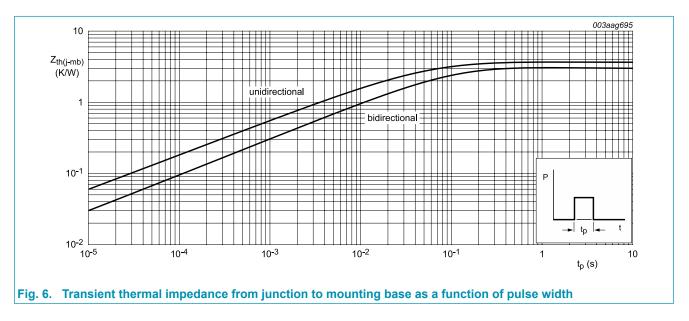






8. Thermal characteristics

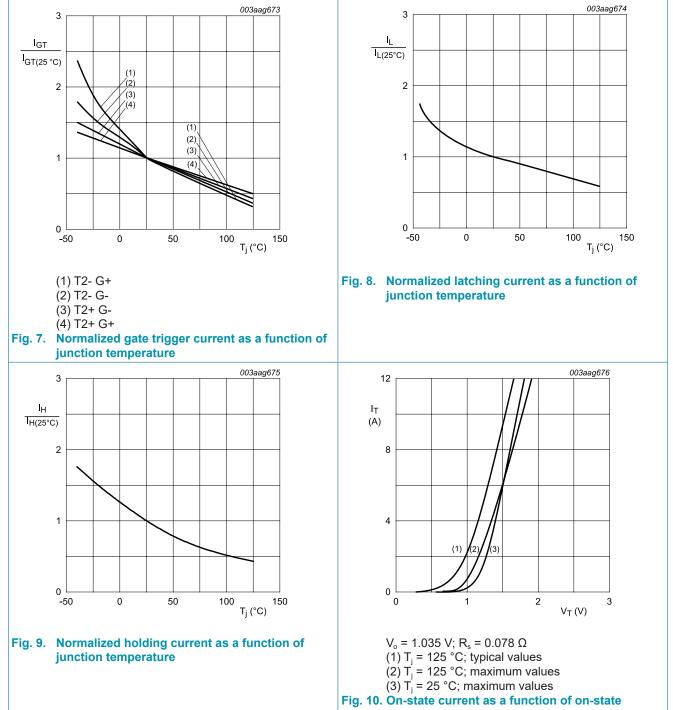
Table 5. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	full cycle; <u>Fig. 6</u>		-	-	3.7	K/W
		half cycle; <u>Fig. 6</u>		-	-	3	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air		-	60	-	K/W



9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
	aracteristics				indix	
I _{GT}	gate trigger current	$V_{D} = 12 V; I_{T} = 0.1 A; T2+ G+;$ T _i = 25 °C; <u>Fig. 7</u>	-	-	5	mA
		$V_{\rm D}$ = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; Fig. 7	-	-	5	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ $T_{j} = 25 \text{ °C}; \text{ Fig. 7}$	-	-	5	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G+};$ $T_{j} = 25 \text{ °C}; \text{ Fig. 7}$	-	-	10	mA
ΙL	latching current	$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; Fig. 8	-	-	10	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; Fig. 8	-	-	15	mA
		V_{D} = 12 V; I_{G} = 0.1 A; T2- G-; T _j = 25 °C; Fig. 8	-	-	10	mA
		V_{D} = 12 V; I_{G} = 0.1 A; T2- G+; T _j = 25 °C; Fig. 8	-	-	10	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	6	mA
V _T	on-state voltage	$I_{T} = 6 \text{ A}; T_{j} = 25 \text{ °C}; Fig. 10$	-	1.3	1.5	V
V _{gt}	gate trigger voltage	$V_{\rm D}$ = 12 V; I _T = 0.1 A;T _j = 25 °C; Fig. 11	-	0.7	1	V
		V _D = 800V; I _T = 0.1 A;T _j = 25 °C; <u>Fig. 11</u>	0.25	0.4	-	V
I _D	off-state current	V _D = 800 V; T _j = 125 °C	-	0.1	0.5	mA
Dynamic	characteristics		I			
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	-	50	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ Tj} = 125 \text{ C}; I_{T(RMS)} = 4 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu\text{s}; \text{ (snubberless condition); gate open circuit}$	-	1.2	-	A/ms
t _{gt}	gate-controlled turn-on time	$I_{TM} = 6 \text{ A}; V_D = 800 \text{ V}; I_G = 0.1 \text{ A};$ $dI_G/dt = 5 \text{ A}/\mu \text{s}$	-	2	-	μs

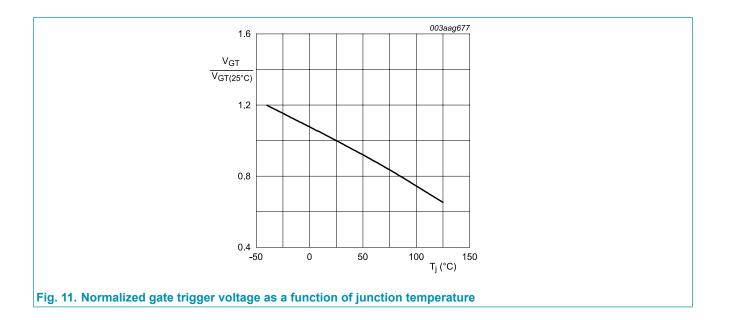
BT234-800D 4Q Triac



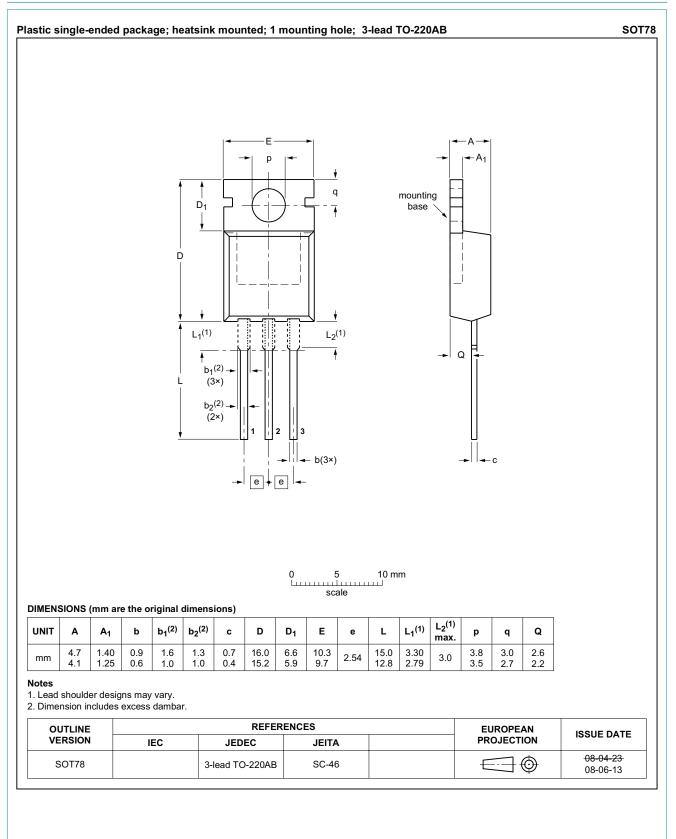
voltage

4Q Triac

BT234-800D



10. Package outline



11. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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